

Remaining Battery Power Display Monolithic IC MM1210

Outline

This IC detects battery voltage and displays the remaining power in the battery using an LCD. Long life and light weight are emphasized in the most recent portable equipment, which increasingly use nickel cadmium and nickel hydrogen batteries. For these batteries, the discharge characteristics mean that extremely precise detection of the remaining battery power is required.

This IC enables detection of this type through high precision voltage detection.

Features

1. Two built-in detection voltages 1.18V / 1.06V typ.
2. High precision detection voltages $\pm 1\%$ typ.
3. Low current consumption During detection ; 15 μ A typ.
 During waiting ; 15 μ A typ.
4. Setting possible during non-induction
It is possible to set a time period for which detection is ignored, as for example when voltage drops due to temporary heavy loads.
5. Ripple absorption pins
It is possible to check fluctuations in detection through continuous rippling.
6. Built-in hysteresis voltage

Package

SOP-8D (MM1210XF)

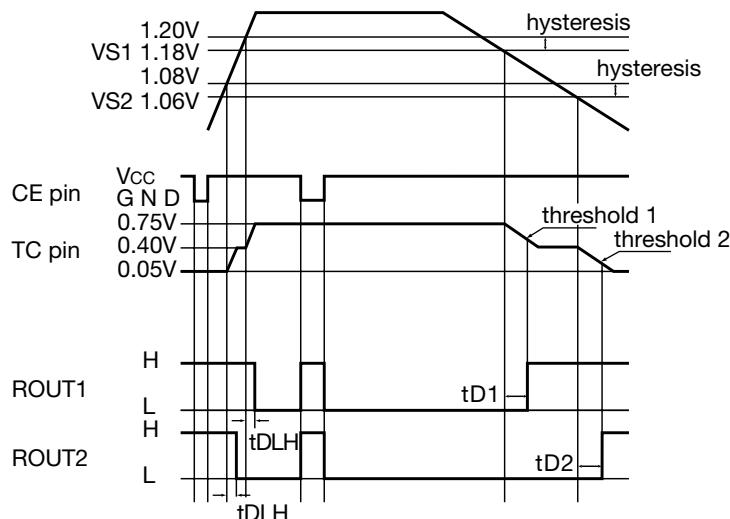
Absolute Maximum Ratings

Item	Rating
Storage temperature	-40~+125°C
Operating temperature	-20~+70°C
Input voltage	5V
Output pin voltage	5V
Allowable loss	300mW

Electrical Characteristics (Unless otherwise specified $T_a=25^\circ C$, $V_{CC}=1.5V$, $V_{CE}=V_{CC}$)

Item	Symbol	Measurement Conditions	Min.	Typ.	Max.	Unit	
Current consumption	I _{CC1}	$V_{CC}=1.5V$		15	25	μA	
Current consumption during waiting	I _{CC2}	$V_{CC}=1.3V$, $V_{CE}=0.3V$		1.5	2.5	μA	
Detection voltage 1	V _{TH1}	$V_{CC}=H \rightarrow L$	1.169	1.180	1.191	V	
Detection voltage 2	V _{TH2}	$V_{CC}=H \rightarrow L$	1.050	1.060	1.070	V	
Detection voltage Difference	ΔV_T	$\Delta V_T = V_{TH1} - V_{TH2}$	100	120	140	mV	
Detection voltage temperature factor				± 200		ppm/ $^\circ C$	
Hysteresis voltage	V _{HYS}		10	20	35	mV	
Output sink current 1	I _{S1}	$V_{CC}=1.3V$, $V_{O1}=0.3V$	40			μA	
Output sink current 2	I _{S2}	$V_{CC}=1.3V$, $V_{O2}=0.3V$	40			μA	
Output saturation voltage 1	V _{O1}	$I_{SINK}=30\mu A$		150	250	mV	
Output saturation voltage 2	V _{O2}	$I_{SINK}=30\mu A$		150	250	mV	
Output leak voltage 1	I _{LE1}	$V_{CC}=1.0V$, $V_{O1}=0.5V$			1	μA	
Output leak voltage 2	I _{LE2}	$V_{CC}=1.0V$, $V_{O2}=1.5V$			1	μA	
Power supply voltage operating limit	V _{OPL}	$V_{CC}=\text{variable}$, $V_O < 0.4V$		0.70	0.75	V	
CE pin	Input H voltage	V _{CEH}		V _{CC} -0.3	V _{CC}	V _{CC} +0.3	V
	Input L current	I _{CEH}	$V_{CC}=1.5V$, $V_{CE}=0V$	100	300	500	nA
	Input L voltage	V _{CEL}		-0.3	0	0.3	V
TC pin	Threshold value 1	V _{THT}	$V_{CC}=1.0V$, $V_{TC}=\text{variable}$	0.34	0.42	0.50	V
	Threshold value 2	V _{THT}	$V_{CC}=1.0V$, $V_{TC}=\text{variable}$	0.04	0.12	0.20	V
	Discharge current	I _{DIS}	$V_{CC}=1.0V$, $V_{TC}=0.5V$	30	60	90	nA
	Charge current	I _{CHA}	$V_{CC}=1.5V$, $V_{TC}=0.5V$	0.40	0.80	1.20	μA
Non-induction time	td	$V_{CC}=1.5V$, $C=0.033\mu F$	120	180	240	ms	
L transmission delay time	tdLH	$V_{CC}=L \rightarrow H$, $C=0.033\mu F$	1.0	2.0	4.0	ms	
Ripple absorption resistance	RRIP	measure resistance between pins 8-6	70	100	130	k Ω	
Note : V _{CC} applied pulse conditions				td1 1.25V GND	td2 1.15V 1.00V		
V _{CC} applied pulse							

Timing Chart



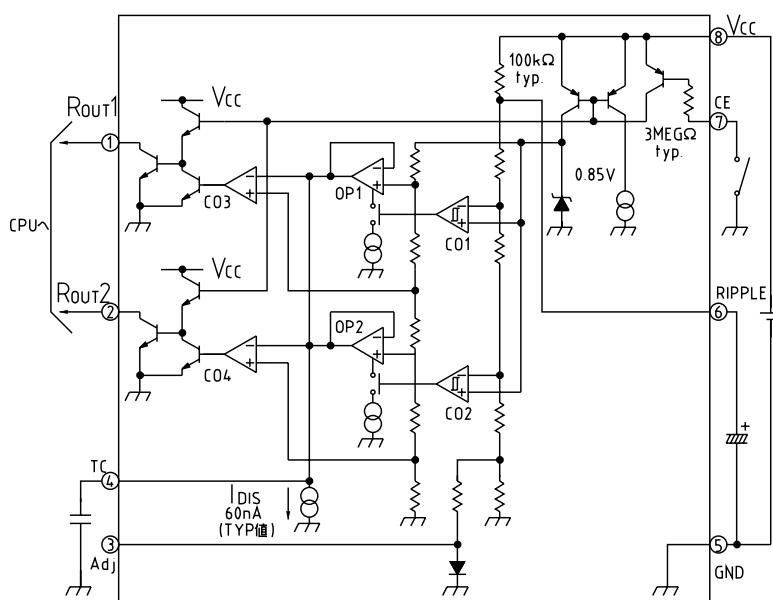
*Delay time is calculated by the following formula :

$$t_{D1}=t_{D2} \text{ (S)} = C_T(F) \times (5.4 \times 10^6)$$

$$t_{DLH} \text{ (S)} = C_T(F) \times (6.3 \times 10^4)$$

C_T , TC pin connection capacitance

Block Diagram, Example of Application Circuit



Output

Vcc	1.18	1.06	
ROUT 1	L	H	H
ROUT 2	L	L	H

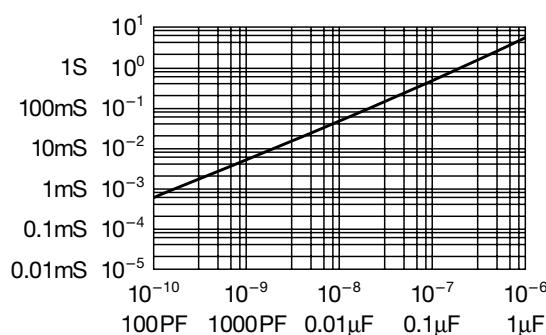
CE pin

H	Operation
L	Waiting

Note 1 : Please connect the CE pin to Vcc when not using.

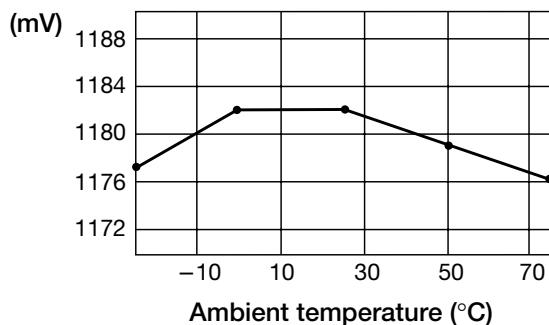
Note 2 : The Adj terminal is used in the product inspection process, so please do not connect it to other wiring.

Capacitance of external capacitor for non-induction time

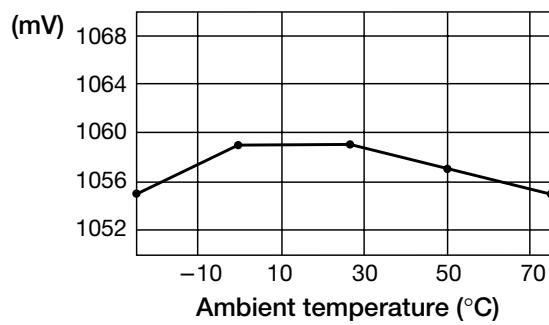


Characteristics

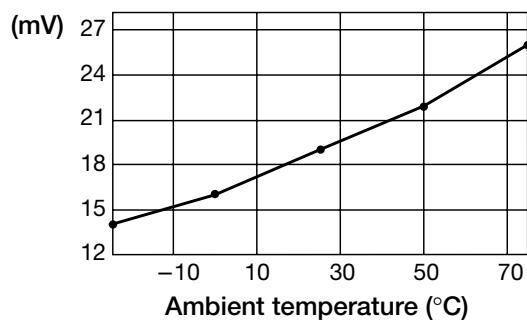
■ Detection voltage 1 Ambient temperature characteristics



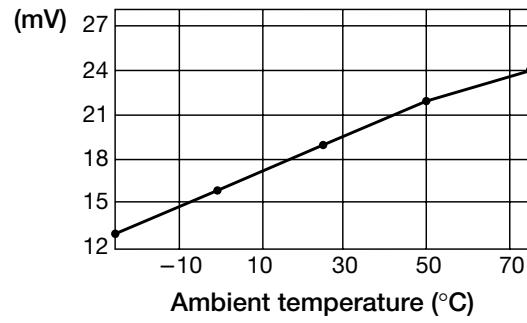
■ Detection voltage 2 Ambient temperature characteristics



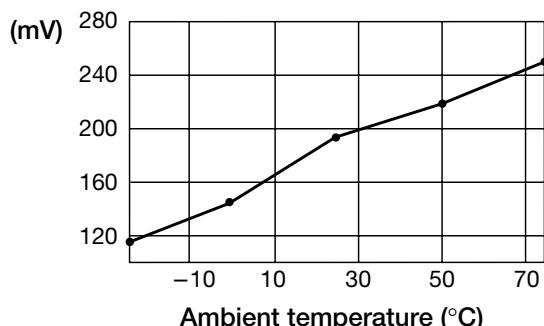
■ Hysteresis voltage 1 Ambient temperature characteristics



■ Hysteresis voltage 2 Ambient temperature characteristics



■ Output saturation voltage 1 Ambient temperature characteristics



■ Output sink current 1 Ambient temperature characteristics

